On the origin of reentrance in 2D Josephson Junction A rrays

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A comparative study of the magnetic properties of shunted and unshunted two-dimensional Josephson junction arrays (2D-JJA) is presented. Using a single-plaquette approximation of the 2D-JJA model, we were able to successfully tallour experimental data (for the temperature, AC and DC eld dependencies of susceptibility) and demonstrate that the dynamic reentrance of AC susceptibility is directly linked to the value of the Stewart-M cC umber parameter $_{\rm C}$. Based on extensive numerical simulations, a phase diagram $_{\rm C}$ $_{\rm L}$ is plotted which demarcates the border between the reentrant and non-reentrant behavior in the arrays.

I. IN TRODUCTION

According to the current paradigm, param agnetic Meissner e ect (PME) [1{6] can be related to the presence of -junctions [7], either resulting from the presence of m agnetic in purities in the junction [8,9] or from unconventional pairing symmetry [10]. Other possible explanations of this phenom enon are based on ux trapping [11] and ux compression e ects [12] including also an important role of the surface of the sample [3]. Besides, in the experiments with unshunted 2D-JJA, we have previously reported [13] that PME manifests itself through a dynam ic reentrance (DR) of the AC m agnetic susceptibility as a function oftem perature. These results have been further corroborated by N ielsen et al. [14] and De Leo et al. [15] who argued that PM E can be simply related to magnetic screening in multiply connected superconductors. So, the main question is: which parameters are directly responsible for the presence (or absence) of DR in articially prepared arrays?

P reviously (also within the single plaquette approximation), Barbara et al. [13] have brie y discussed the e ects of varying $_{\rm L}$ on the observed dynam ic reentrance with the main emphasis on the behavior of 2D -JJA sam - ples with high (and xed) values of $_{\rm C}$. How ever, to our know ledge, up to date no systematic study (either experimental or theoretical) has been done on how the $_{\rm C}$ value itselfa ects the reentrance behavior. In the present

work, by a comparative study of the magnetic properties of shunted and unshunted 2D -JJA, we propose an answer to this open question. Namely, by using experimental and theoretical results, we will demonstrate that only arrays with su ciently large value of the Stewart-McCumber parameter $_{\rm C}$ will exhibit the dynamic reentrance behavior (and hence PME).

II. EXPER IM EN TAL RESULTS

To measure the complex AC susceptibility in our arrays we used a high-sensitive hom e-m ade susceptom eter based on the so-called screening method in the rejection con guration [16{18]. The experimental system was calibrated by using a high-quality niobium thin lm. P reviously [18], we have shown that the calibrated output complex voltage of the experimental setup corresponds to the complex AC susceptibility.

To experim entally investigate the origin of the reentrance, we have measured $^{0}(T)$ for three sets of shunted and unshunted samples obtained from di erent makers (W estinghouse and Hypress) under the same conditions of the amplitude of the excitation $eld h_{ac}$ (1m 0 e < h_{ac} < 100 e), external magnetic eld H_{dc} (0 < H $_{dc}$ < 5000 e) parallel to the plane of the sample, and frequency of AC eld ! = 2 f (xed at f = 20kH z). Unshunted 2D -JJAs are formed by loops of niobium islands linked through N b A 10x N b Josephson junctions while shunted 2D -JJAs have a molybdenum shunt resistor (with R $_{\rm sh}$ ' 2:2) short-circuiting each junction (see Fig.1). Both shunted and unshunted sam ples have rectangular geometry and consist of 100 150 tunnel junctions. The unit cell for both types of arrays has square geom etry with lattice spacing a ' 46 m and a single junction area of 5 m². The critical current density for the junctions form ing the arrays is about 600A = m^2 at 4.2K . Besides, for the unshunted samples $_{\rm C}$ (4.2K) ' 30 and $_{\rm L}$ (4.2K) ' 30, while for shunted sam ples $_{\rm C}$ (4.2K) ' 1 and $_{L}$ (4.2K) ' 30 where [19] $_{L}$ (T) = $\frac{2 L I_{C}$ (T)}{2} and $_{\rm C}$ (T) = $\frac{2 C_{\rm J} R_{\rm J}^2 I_{\rm C}$ (T)}{2 C_{\rm J} R_{\rm J}^2 I_{\rm C} (T). Here, $C_{\rm J}$ ' 0:58pF is the capacitance, R_J / 10:4 the quasi-particle resistance (of unshunted array), and I_c (4.2K) ' 150 A critical current of the Josephson junction. $_0$ is the quantum of

m agnetic ux. The param eter $_{\rm L}$ is proportional to the number of ux quanta that can be screened by the maximum critical current in the junctions, while the Stewart-M cC umber param eter $_{\rm C}$ basically release the quality of the junctions in arrays.

It is well established that both m agnetic and transport properties of any superconducting m aterial can be described via a two-com ponent response [20], the intragranular (associated with the grains exhibiting bulk superconducting properties) and intergranular (associated with weak-link structure) contributions [21,22]. Likewise, arti cially prepared JJAs (consisting of superconducting islands, arranged in a symm etrical periodic lattice and coupled by Josephson junctions) will produce a similar response [23].

Since our shunted and unshunted samples have the same value of $I_{\rm L}$ and di erent values of $C_{\rm C}$, it is possible to verify the dependence of the reentrance e ect on the value of the Stewart-M cC um ber parameter. For the unshunted 2D-JJA (Fig. 2a) we have found that eld lower than 50m 0 e (when the array is for an AC in the M eissner-like state) the behavior of ${}^{0}(T)$ is quite sim ilar to hom ogeneous superconducting sam ples, while for h_{ac} > 50m 0 e (when the array is in the mixedlike state with practically hom ogeneous ux distribution) these samples exhibit a clear reentrant behavior of susceptibility [13]. At the same time, the identical experin ents perform ed on the shunted sam ples produced no evidence of any reentrance for all values of hac (see Fig. 2b). It is important to point out that the analysis of the experim entally obtained in aginary component of susceptibility $^{00}(T)$ shows that for the highest AC magnetic

eld am plitudes (of about 200m O e) dissipation rem ains sm all. N am ely, for typical values of the AC am plitude, $h_{ac} = 100m$ O e (which corresponds to about 10 vortices per unit cell) the imaginary component is about 15 times sm aller than its real counterpart. Hence contribution from the dissipation of vortices to the observed phenom – ena can be safely neglected.

To further study this unexpected behavior we have also performed experiments where we measure $^{0}(T)$ for different values of H_{dc} keeping the value of h_{ac} constant. The in uence of DC elds on reentrance in unshunted samples is shown in Fig. 3. On the other hand, the shunted samples still show no signs of reentrance, follow – ing a familiar pattern of eld-induced gradual diminishing of superconducting phase (very similar to a zero DC eld at-like behavior seen in Fig.2b).

To understand the in uence of DC eld on reentrance observed in unshunted arrays, it is in portant to emphasize that for our sample geometry this parallel eld suppresses the critical current I_c of each junction without introducing any detectable ux into the plaquettes of the array. Thus, a parallel DC m agnetic eld allows us to vary I_c independently from temperature and/or applied perpendicular AC eld. The m easurem ents show

(see Fig.3) that the position of the reentrance is tuned by H_{dc} . We also observe that the value of temperature $T_{m in}$ (at which $^{0}(T)$ has a minimum) rst shifts towards lower tem peratures as we raise H_{dc} (for small DC elds) and then bounces back (for higher values of H_{dc}). This non-monotonic behavior is consistent with the weakening of $I_{\rm C}$ (T) and corresponds to Fraunhoferlike dependence of the Josephson junction critical current on D C m agnetic eld applied in the plane of the junction. Wemeasured I_C from transport current-voltage characteristics, at di erent values of H_{dc} at T = 4.2K and found that ${}^{0}(T = 4.2K)$, obtained from the isotherm T = 4.2K (similar to that given in Fig.3), shows the sam e Fraunhofer-like dependence on H $_{\rm dc}$ as the critical current I_C (H $_{dc}$) of the junctions form ing the array (see Fig.4). This gives further proof that only the junction critical current is varied in this experiment. This also indicates that the screening currents at low tem perature (i.e., in the reentrant region) are proportional to the critical currents of the junctions. In addition, this shows an alternative way to obtain I_{C} (H $_{dc}$) dependence in big arrays. And nally, a sharp Fraunhofer-like pattern observed in both arrays clearly re ects a rather strong coherence (with negligible distribution of critical currents and sizes of the individual junctions) which is based on highly correlated response of all single junctions form ing the arrays, thus proving their high quality. Such a unique behavior of Josephson junctions in our samples provides a necessary justi cation for suggested theoretical interpretation of the obtained experim ental results. Namely, based on the above-m entioned properties of our arrays, we have found that practically all the experim ental results can be explained by analyzing the dynam ics of just a single unit cell in the array.

III. THEORETICAL INTERPRETATION AND NUMERICAL SIMULATIONS

To understand the di erent behavior of the AC susceptibility observed in shunted and unshunted 2D -JJAs, in principle one would need to analyze in detail the ux dynam ics in these arrays. However, as we have previously reported [13], because of the well-de ned periodic structure of our arrays (with no visible distribution of junction sizes and critical currents), it is reasonable to expect that the experim ental results obtained from the m agnetic properties of our 2D -JJAs can be quite satisfactory explained by analyzing the dynam ics of a single unit cell (plaquette) of the array. An excellent agreem ent between a single-loop approximation and the observed behavior (seen through the data ts) justi es a posteriori our assumption. It is important to mention that the idea to use a single unit cell to qualitatively understand PME was rst suggested by Auletta et al. [24]. They simulated the eld-cooled DC magnetic susceptibility of

a single-junction loop and found a param agnetic signal at low values of external magnetic eld.

In our calculations and num erical simulations, the unit cell is a loop containing four identical Josephson junctions and the measurements correspond to the zero-eld cooling (ZFC) AC magnetic susceptibility. We consider the junctions of the single unit cell as having capacitance C_J , quasiparticle resistance R_J and critical current I_C . We have used this simple four-junctions model to study the magnetic behavior of our 2D -JJA by calculating the AC complex magnetic susceptibility = 0 + i 00 as a function of T, $_C$ and $_L$. Speci cally, shunted samples are identified through low values of the M cC umber parameter ($_C$ 1) while high values ($_C$ 1) indicate an unshunted 2D -JJA.

If we apply an AC external eld $B_{ac}(t) = {}_{0}h_{ac}\cos!t$ norm ally to the 2D-JJA and a DC eld $B_{dc} = {}_{0}H_{dc}$ parallel to the array, then the total magnetic ux (t) threading the four-junction superconducting bop is given by (t) = ${}_{ext}(t) + LI(t)$ where L is the loop inductance, ${}_{ext}(t) = SB_{ac}(t) + LB_{dc}$ is the ux related to the applied magnetic eld (with 1 d being the size of the single junction area, and S ' a² being the projected area of the loop), and the circulating current in the loop reads

$$I(t) = I_{C}(T) \sin_{i}(t) + \frac{0}{2 R_{J}} \frac{d_{i}}{dt} + \frac{C_{J}}{2} \frac{0}{dt^{2}} \frac{d^{2}}{dt^{2}}$$
(1)

Here $_{\rm i}\,(t)$ is the gauge-invariant superconducting phase di erence across the ith junction, and $_0$ is the magnetic ux quantum .

Since the inductance of each loop is $L = _0 a' 64pH$ and the critical current of each junction is $I_{\rm C}$ ' 150 A, for the mixed-state region (above 50m 0 e) we can safely neglect the self-eld e ects because in this region LI(t) is always smaller than ext (t). Besides, since the length l and the width w of each junction in our array is smaller than the Josephson penetration depth $_{\rm J}$ = $_0=2$ $_0dj_{c0}$ (where j_{c0} is the critical current density of the junction, and $d = 2_{L} + is$ the size of the contact area with $_{\rm L}$ (T) being the London penetration depth of the junction and an insulator thickness), namely 1' w ' 5 m and $_{\rm J}$ ' 20 m (using j_{c0} ' 600A = cm² and $_{L}$ ' 39nm for N b at T = 42K), we can adopt the sm all-junction approxim ation [19] for the gauge-invariant superconducting phase di erence across the ith junction (for simplicity we assume as usual [13] that $_1 = _2 =$ $_{3} = _{4} _{i})$

$$_{i}(t) = _{0}(H_{dc}) + \frac{2 B_{ac}(t)S}{_{0}}$$
 (2)

where $_0(H_{dc}) = _0(0) + 2 _0H_{dc}dl = _0$ with $_0(0)$ being the initial phase di erence.

To properly treat the magnetic properties of the system, let us introduce the following Ham iltonian

H (t) =
$$J \prod_{i=1}^{X^4} [L \cos_i(t)] + \frac{1}{2} L L^2(t)$$
 (3)

which describes the tunneling (rst term) and inductive (second term) contributions to the total energy of a single plaquette. Here, J (T) = ($_0=2$)I_c (T) is the Josephson coupling energy.

The real part of the complex AC susceptibility is dened as

$${}^{0}(\mathbf{T};\mathbf{h}_{ac};\mathbf{H}_{dc}) = \frac{@M}{@h_{ac}}$$
(4)

where

$$M (T;h_{ac};H_{dc}) = \frac{1}{V} \frac{@H}{@h_{ac}}$$
(5)

is the net m agnetization of the plaquette. Here V is the sam ple's volume, and < :::> denotes the time averaging over the period 2 =!, namely

$$< A > = \frac{1}{2} \int_{0}^{Z_{2}} d(! t)A(t)$$
 (6)

Taking into account the well-known [25] analytical approximation of the BCS gap parameter (valid for all tem – $q \frac{T_{c} T}{T}$ for the explicit tem perature dependence of the Josephson critical current

$$I_{C}$$
 (T) = I_{C} (0) $\frac{(T)}{(0)}$ tanh $\frac{(T)}{2k_{B}T}$ (7)

we successfully tted all our data using the following set of parameters: $_0(0) = \frac{1}{2}$ (which corresponds to the maximum Josephson current within a plaquette), $_L(0) = 32$, $_C(0) = 32$ (for unshunted array) and $_C(0) = 12$ (for shunted array). The corresponding ts are shown by solid lines in Figs2 and 3 for the experimental values of AC and DC eld am plitudes.

In the mixed-state region and for low enough frequencies (this assumption is well-satisfied because in our case ! $p!_{LR}$ and ! ! $_{LC}$ where ! $_{LR} = R = L$ and ! $_{LC} = 1 = LC$ are the two characteristic frequencies of the problem) from Eqs.(3)-(6) we obtain the following approximate analytical expression for the susceptibility of the plaquette

$${}^{0}(T;h_{ac};H_{dc}) \,\prime \qquad_{0}(T) \left[{}_{L}(T)f_{1}(b) \cos \frac{2H_{dc}}{H_{0}} \right]$$
(8)
+ $f_{2}(b) \sin \frac{H_{dc}}{H_{0}} {}_{c}^{1}(T)$

where $_{0}$ (T) = $S^{2}I_{c}$ (T)=V $_{0}$, H $_{0}$ = $_{0}$ =(2 $_{0}$ dl) ' 100 e, f₁ (b) = J_{0} (2b) J_{2} (2b), and f₂ (b) = J_{0} (b) bJ₁ (b) $3J_{2}$ (b) + bJ₃ (b) with b = 2 S $_{0}h_{ac}$ = $_{0}$ and J_{n} (x) being the Bessel function of the nth order. Notice also that the analysis of Eq.(8) reproduces the observed Fraunhofer-like behavior of the susceptibility in applied DC eld (see Fig.4) and the above-mentioned ne tuning of the reentrance e ect (see also R ef.13). Indeed, according to Eq.(8) (and in agreement with the observations), for small DC elds the minimum temperature $T_{m \ in}$ (indicating the beginning of the reentrant transition) varies with H dc as follows, 1 $T_{m \ in} = T_C$ ' H dc=H o.

To further test our interpretation and verify the in uence of the param etcr $_{\rm C}$ on the reentrance, we have also perform ed extensive num erical simulations of the fourjunction m odel previously described but without a sim – plifying assumption about the explicit form of the phase di erence based on Eq.(2). More precisely, we obtained the tem perature behavior of the susceptibility by solving the set of equations responsible for the ux dynam – ics within a single plaquette and based on Eq.(1) for the total current I (t), the equation for the total ux

(t) = $_{ext}$ (t) + LI(t) and the ux quantization condition for four junctions, nam ely $_{1}$ (t) = $_{\overline{2}}$ n + $_{0}$ where n is an integer. Both Euler and fourth-order Runge-Kutta integration m ethods provided the sam e num erical results. In Fig.5 we show the real component of the sim ulated susceptibility (T) corresponding to the xed value of $_{C}$ (T = 42K) = 1 (shunted sam ples) and di erent values of $_{L}$ (T = 42K) = 1,10,15,20,30,40,50,60,90, 150 and 200. As expected, for this low value of $_{C}$ reentrance is not observed for any values of $_{L}$. On the other hand, Fig.6 shows the real component of the sim ulated

(T) but now using xed value of $_{\rm L}$ (T = 42K) = 30 and di erent values of $_{\rm C}$ (T = 42K) = 1, 2, 5, 10, 20, 30 and 100. This gure clearly shows that reentrance appears for values of $_{\rm C}$ > 20. In both cases we used $h_{\rm ac}$ = 70m O e. We have also simulated the curve for shunted ($_{\rm L}$ = 30, $_{\rm C}$ = 1) and unshunted ($_{\rm L}$ = 30, $_{\rm C}$ = 30) samples for di erent values of $h_{\rm ac}$ (see Fig.7). In this case the values of the parameters $_{\rm L}$ and $_{\rm C}$ were chosen from our real 2D -JJA samples. Again, our simulations con m that dynamic reentrance does not occur for low values of $_{\rm C}$, independently of the values of $_{\rm L}$ and $h_{\rm ac}$.

The following comment is in order regarding some irregularities visibly seen in Figs.(5)–(7) around the transition regions from non-reentrant to reentrant behavior. It is important to emphasize that the above irregularities are just artifacts of the numerical simulations due to the conventional slow-converging real-time reiteration procedures [13]. They neither correspond to any experimentally observed behavior (within the accuracy of the measurements technique and data acquisition), nor they rejudence seen through the data ts). As usual, to avoid this kind of articial (non-physical) discontinuity, more powerful computers are needed.

Based on the above extensive numerical simulations, a resulting phase diagram $_{\rm C}$ $_{\rm L}$ (taken for T = 1K, $h_{\rm ac}$ = 70m O e, and H $_{\rm dc}$ = 0) is depicted in Fig.8 which clearly demarcates the border between the reentrant (white area) and non-reentrant (shaded area) behavior in the arrays for di erent values of $_{\rm L}$ (T) and $_{\rm C}$ (T) param eters at given temperature. In other words, if $_{\rm L}$ and $_{\rm C}$ param eters of any realistic array have the values inside the white area, this array will exhibit a reentrant behavior. In addition, this diagram shows that one can prepare a reentrance exhibiting array by changing one of the param eters (usually, it is much easier to change $_{\rm C}$ by tuning the shunt resistance rather than the geom etry related inductance param eter $_{\rm L}$).

It is instructive to m ention that a hyperbolic-like character of $_{\rm L}$ vs $_{\rm C}$ law (seen in Fig.8) is virtually present in the approximate analytical expression for the susceptibility of the plaquette given by Eq.(8) (notice how ever that this expression can not be used to produce any quantitative prediction because the neglected in Eq.(8) frequencyrelated terms depend on $_{\rm L}$ and $_{\rm C}$ parameters as well). A qualitative behavior of the envelope of the phase diagram (depicted in Fig.8) with DC m agnetic eld H_{dc} (for T = 1K and h_{ac} = 70m O e), obtained using Eq.(8), is shown in Fig.9.

And nally, to understand how small values of $_{\rm C}$ parameter a ect the ux dynamics in shunted arrays, we have analyzed the tot (ext) diagram. Sim ilarly to those results previously obtained from unshunted sam ples [13], for a shunted sample at xed tem perature this curve is also very hysteretic (see Fig.10). In both cases, tot vs. ext shows multiple branches intersecting the line tot = 0 which corresponds to diam agnetic states. For all the other branches, the intersection with the line tot = ext corresponds to the boundary between diam agnetic states (negative values of 0) and param agnetic states (positive values of ⁰). As we have reported before [13], for unshunted 2D -JJA at tem peratures below 7:6K the appearance of the rst and third branches adds a param agnetic contribution to the average value of 0 . W hen $_{\rm C}$ is small (shunted arrays), the analysis of these curves shows that there is no reentrance at low temperatures because in this case the second branch appears to be energetically stable, giving an extra diam agnetic contribution which overwhelm s the param agnetic contribution from subsequent branches. In other words, for low enough values of $_{\rm C}$ (when the samples are ZFC and then m easured at sm all values of the m agnetic eld), m ost of the bops will be in the diam agnetic states, and no paramagnetic response is registered. As a result, the ux quanta cannot get trapped into the loops even by the following eld-cooling process in small values of the magnetic eld. In this case the superconducting phases and the junctions will have the sam e diam agnetic response and the resulting measured value of the magnetic susceptibility will be negative (i.e., diam agnetic) as well. On

the other hand, when $_{\rm C}$ is large enough (unshunted arrays), the second branch becom es energetically unstable, and the average response of the sam ple at low tem peratures is param agnetic (C f. F ig.7 from R ef. [13]).

In conclusion, our experimental and theoretical results have demonstrated that the reentrance phenomenon (and concomitant PME) in articially prepared Josephson Junction Arrays is related to the damping elects associated with the Stewart-MCC umber parameter $_{\rm C}$. Namely, reentrant behavior of AC susceptibility takes place in the underdamped (unshunted) array (with large enough value of $_{\rm C}$) and totally disappears in overdamped (shunted) arrays.

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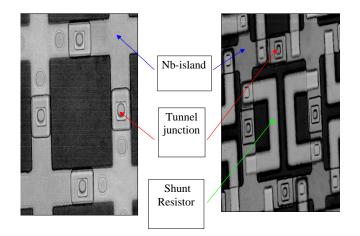


FIG.1. Left: photograph of the unshunted array; right: photograph of the shunted array.

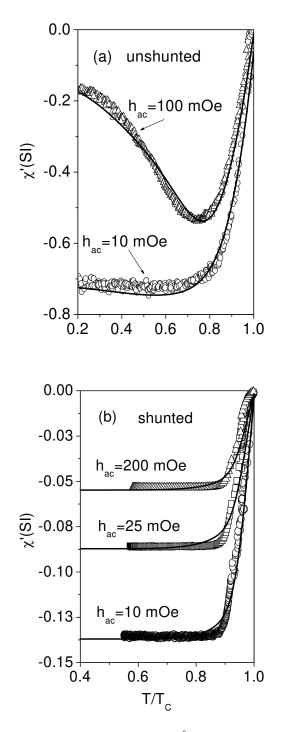


FIG.2. Experimental results for ${}^{0}(T;h_{ac};H_{dc})$: (a) unshunted 2D-JJA for h_{ac} = 10 and 100m Oe; (b) shunted 2D-JJA for h_{ac} = 10, 25, and 200m Oe. In all these experiments H_{dc} = 0. Solid lines are the best ts (see text).

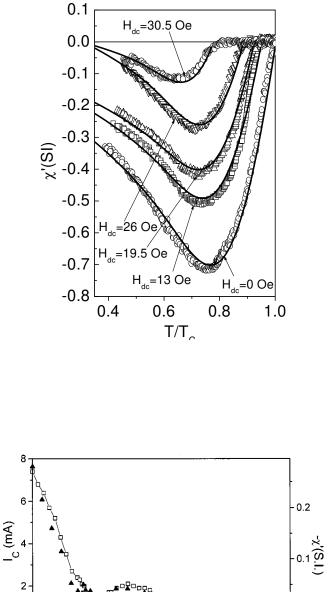


FIG.4. The critical current $I_{\rm C}$ (open squares) and the real part of AC susceptibility 0 (solid triangles) as a function of DC $\,$ eld H $_{\rm dc}$ for T = 4.2K (from Ref.13).

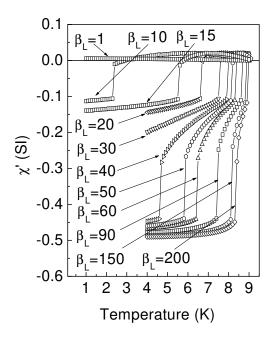


FIG.5. Numerical simulation results for $h_{ac} = 70m \text{ Oe}$, $H_{dc} = 0$, $_{c}$ (T = 4.2K) = 1 and for dierent values of $_{L}$ (T = 4.2K) based on Eqs.(4)-(7).

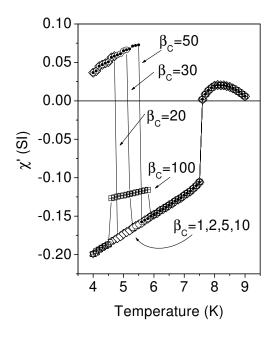


FIG.6. Numerical simulation results for $h_{ac} = 70m \text{ Oe}$, H_{dc} = 0, L(T = 42K) = 30 and for dierent values of c(T = 42K) based on Eqs.(4)-(7).

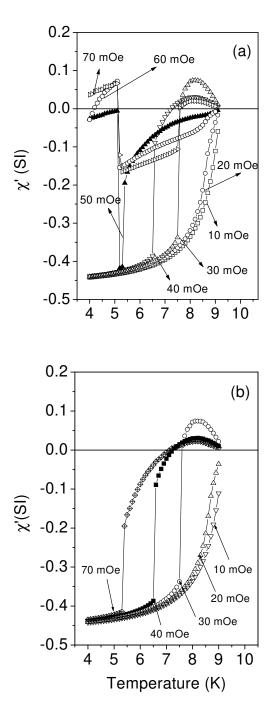


FIG.7. Curves of the simulated susceptibility (for $H_{dc} = 0$ and for dimensional event values of h_{ac}) corresponding to (a) unshunted 2D -JJA with _L (T = 4.2K) = 30 and _C (T = 4.2K) = 30; (b) shunted 2D -JJA with _L (T = 4.2K) = 30 and _C (T = 4.2K) = 1.

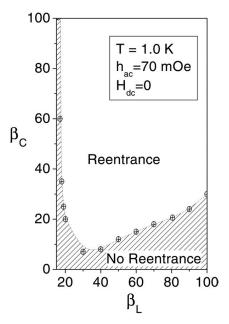


FIG.8. Numerically obtained phase diagram (taken for T = 1K, $h_{ac} = 70m Oe$, and $H_{dc} = 0$) which shows the border between the reentrant (white area) and non-reentrant (shaded area) behavior in the arrays for di erent values of $_L$ and $_c$ parameters

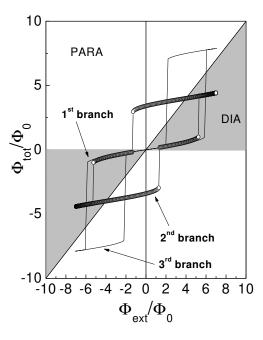


FIG.10. Numerical simulation results showing $_{\rm tot}$ vs. $_{\rm ext}$ for shunted 2D-JJA with $_{\rm L}$ (T = 4.2K) = 30 and $_{\rm C}$ (T = 4.2K) = 1.

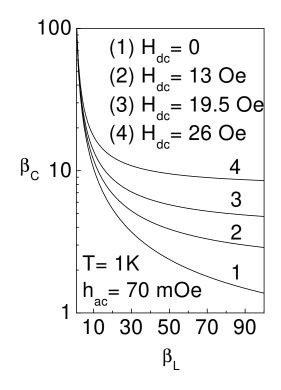


FIG.9. A qualitative behavior of the envelope of the phase diagram (shown in previous gure) with DC magnetic eld H $_{dc}$ (for T = 1K and h_{ac} = 70m O e) obtained from Eq.(8).